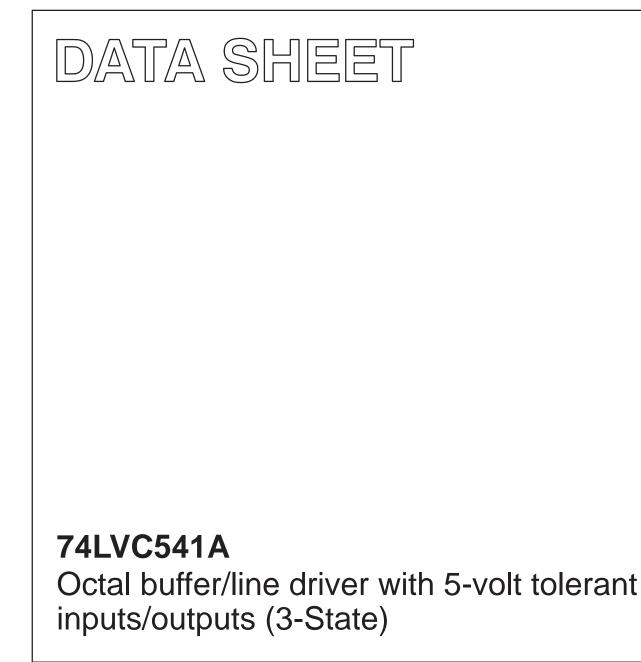
# INTEGRATED CIRCUITS



Product specification Supercedes data of 1997 Oct 27 IC24 Data Handbook

1998 Jul 29



# Octal buffer/line driver with 5-volt tolerant inputs/outputs (3-State)

# 74LVC541A

#### FEATURES

- 5-volt tolerant inputs/outputs, for interfacing with 5-volt logic
- Wide supply voltage range of 2.7V to 3.6V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- Direct interface with TTL levels
- 5 Volt tolerant inputs/outputs, for interfacing with 5 Volt logic

#### DESCRIPTION

The 74LVC541A is a high performance, low-power, low-voltage Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

Inputs can be driven from either 3.3V or 5.0V devices. In 3-State operation, outputs can handle 5V. This feature allows the use of these devices as translators in a mixed 3.3V/5V environment.

The 74LVC541A is an octal non-inverting buffer/line driver with 5-volt tolerant inputs/outputs. The 3-State outputs are controlled by the output enable inputs  $\overline{OE1}$  and  $\overline{OE2}$ .

## QUICK REFERENCE DATA

GND = 0 V;  $T_{amb} = 25^{\circ}C$ ;  $t_r = t_f \le 2.5 \text{ ns}$ 

SYMBOL	PARAMETER	PARAMETER CONDITIONS		UNIT
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay An to Yn	$\begin{array}{l} C_{L}=50 \text{ pF};\\ V_{CC}=3.3 \text{ V} \end{array}$	3.3	ns
Cl	Input capacitance		5.0	pF
C <sub>PD</sub>	Power dissipation capacitance per buffer	Notes 1 and 2	20	pF

#### NOTES:

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ )  $P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum (C_L \times V_{CC}^2 \times f_o)$  where:  $f_i$  = input frequency in MHz;  $C_L$  = output load capacitance in pF;  $f_o = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in V;}$  $\sum (C_L \times V_{CC}^2 \times f_o) = \text{sum of the outputs.}$ 

2. The condition is  $V_I = GND$  to  $V_{CC}$ 

#### ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	PKG. DWG. #
20-Pin Plastic SO	–40°C to +85°C	74LVC541A D	74LVC541A D	SOT163-1
20-Pin Plastic SSOP Type II	–40°C to +85°C	74LVC541A DB	74LVC541A DB	SOT339-1
20-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC541A PW	7LVC541APW DH	SOT360-1

#### **PIN DESCRIPTION**

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 19	<u>OE</u> 1, <u>OE</u> 2	Output enable inputs (active LOW)
2, 3, 4, 5, 6, 7, 8, 9	A0 to A7	Data inputs
10	GND	Ground (0 V)
18, 17, 16, 15, 14, 13, 12, 11	Y0 to Y7	Bus outputs
20	V <sub>CC</sub>	Positive supply voltage

## **FUNCTION TABLE**

INPUTS	INPUTS		OUTPUT
OE1	OE2	An	Yn
L	L	L	L
L	L	Н	Н
Х	Н	Х	Z
Н	Х	Х	Z

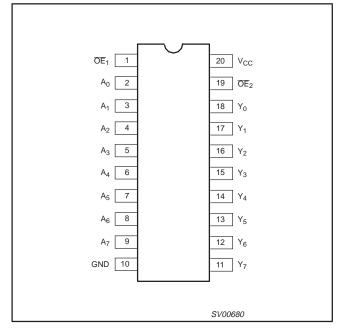
H = HIGH voltage level

L = LOW voltage level

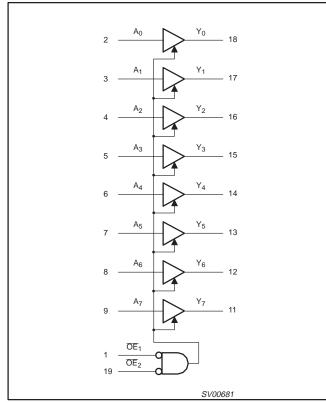
X = don't care

Z = high impedance OFF-state

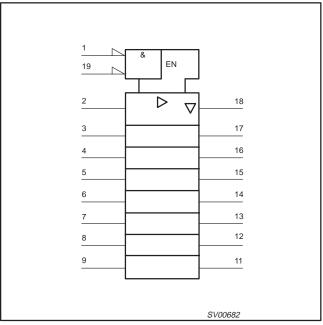
### **PIN CONFIGURATION**



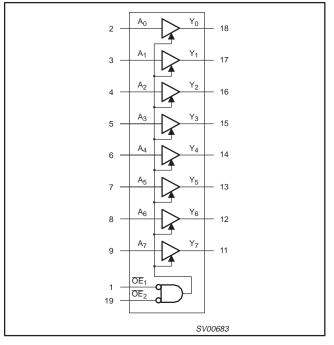
## LOGIC SYMBOL



## LOGIC SYMBOL (IEEE/IEC)



## FUNCTIONAL DIAGRAM



## **RECOMMENDED OPERATING CONDITIONS**

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT		
STWIDOL	FARAMETER	CONDITIONS	MIN	MAX	<b>U</b>	
V <sub>cc</sub>	DC supply voltage (for max. speed performance)		2.7	3.6	V	
VCC	DC supply voltage (for low-voltage applications)		1.2	3.6	v	
VI	DC input voltage range		0	5.5	V	
Vo	DC output voltage range; output HIGH or LOW state		0	V <sub>CC</sub>	V	
v0	DC output voltage range; output 3-State		0	5.5	v	
T <sub>amb</sub>	Operating free-air temperature range		-40	+85	°C	
t <sub>r</sub> , t <sub>f</sub>	Input rise and fall times	V <sub>CC</sub> = 1.2 to 2.7V V <sub>CC</sub> = 2.7 to 3.6V	0 0	20 10	ns/V	

## ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT	
V <sub>CC</sub>	DC supply voltage		-0.5 to +6.5	V	
I <sub>IK</sub>	DC input diode current	V <sub>1</sub> < 0	-50	mA	
VI	DC input voltage	Note 2	-0.5 to +5.5	V	
I <sub>OK</sub>	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	±50	mA	
Vo	DC output voltage; output HIGH or LOW	Note 2	–0.5 to V <sub>CC</sub> +0.5	V	
	DC output voltage; output 3-State	Note 2	-0.5 to +6.5	1	
Ι <sub>Ο</sub>	DC output diode current	$V_{O} = 0$ to $V_{CC}$	±50	mA	
I <sub>GND</sub> , I <sub>CC</sub>	DC V <sub>CC</sub> or GND current		±100	mA	
T <sub>stg</sub>	Storage temperature range		-60 to +150	°C	
P <sub>TOT</sub>	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW	

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

## **DC ELECTRICAL CHARACTERISTICS**

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

			L	UNIT			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -40°C to +85°C				
			MIN	MIN TYP <sup>1</sup> M		AX	
M		V <sub>CC</sub> = 1.2V	V <sub>CC</sub>			V	
VIH	HIGH level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V	2.0			1 `	
M		V <sub>CC</sub> = 1.2V			GND	V	
VIL	LOW level Input voltage	V <sub>CC</sub> = 2.7 to 3.6V			0.8	1 `	
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12mA$	V <sub>CC</sub> -0.5				
M	HIGH level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu A$	V <sub>CC</sub> -0.2	V <sub>CC</sub>		v	
V <sub>OH</sub>		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -18\text{mA}$	V <sub>CC</sub> -0.6				
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -24\text{mA}$	V <sub>CC</sub> -0.8			1	
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12mA$			0.40		
V <sub>OL</sub>	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$			0.20	V	
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = 24\text{mA}$			0.55	1	
l	Input leakage current	$V_{CC} = 3.6V; V_I = 5.5V \text{ or GND}$		±0.1	±5	μA	
I <sub>OZ</sub>	3-State output OFF-state current	$V_{CC} = 3.6V; V_I = V_{IH} \text{ or } V_{IL}; V_O = 5.5V \text{ or GND}$		0.1	±5	μA	
I <sub>OFF</sub>	Power off leakage supply	$V_{CC} = 0.0V; V_{I} \text{ or } V_{O} = 5.5V$			±10	μA	
I <sub>CC</sub>	Quiescent supply current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or } \text{GND}; I_O = 0$		0.1	10	μΑ	
$\Delta I_{CC}$	Additional quiescent supply current per input pin	$V_{CC}$ = 2.7V to 3.6V; $V_{I}$ = $V_{CC}$ –0.6V; $I_{O}$ = 0		5	500	μA	

#### NOTES:

1. All typical values are at  $V_{CC} = 3.3V$  and  $T_{amb} = 25^{\circ}C$ . 2. The specified overdrive current at the data input forces the data input to the opposite logic input state.

## **AC CHARACTERISTICS**

GND = 0 V;  $t_r = t_f \le 2.5 \text{ ns}$ ;  $C_L = 50 \text{ pF}$ 

			LIMITS				-			
SYMBOL	PARAMETER	WAVEFORM	V <sub>CC</sub>	= 3.3V ±0	).3V	١	/ <sub>CC</sub> = 2.7\	/	V <sub>CC</sub> = 1.2V	UNIT
			MIN	TYP <sup>1</sup>	MAX	MIN	TYP	MAX	ТҮР	
t <sub>PHL</sub> /t <sub>PLH</sub>	Propagation delay An to Yn	Figures 1, 3	1.5	3.3	5.6	1.5	3.9	6.6	14	ns
t <sub>PZH</sub> /t <sub>PZL</sub>	3-State output enable time OEn to Yn	Figures 2, 3	1.5	4.4	7.4	1.5	5.2	8.4	2.2	ns
t <sub>PHZ</sub> /t <sub>PLZ</sub>	3-State output disable time OEn to Yn	Figures 2, 3	1.5	3.8	6.0	1.5	4.3	7.0	11	ns

NOTE:

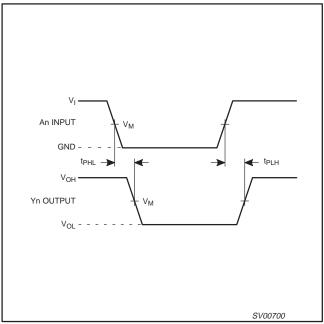
1. Unless otherwise stated, all typical values are at V\_{CC} = 3.3V and T\_{amb} = 25^{\circ}C.

# Octal buffer/line driver with 5-volt tolerant inputs/outputs (3-State)

## 74LVC541A

#### AC WAVEFORMS

 $\begin{array}{l} V_{M} = 1.5 \; V \; at \; V_{CC} \; \geq \; 2.7 \; V \\ V_{M} = 0.5 \bullet V_{CC} \; at \; V_{CC} < 2.7 \; V \\ V_{X} = V_{OL} + 0.3 \; V \; at \; V_{CC} \geq 2.7 \; V \\ V_{X} = V_{OL} + 0.1 \cdot V_{CC} \; at \; V_{CC} < 2.7 \; V \\ V_{Y} = V_{OH} - 0.3 \; V \; at \; V_{CC} \geq 2.7 \; V \\ V_{Y} = V_{OH} - 0.1 \cdot V_{CC} \; at \; V_{CC} < 2.7 \; V \\ V_{OL} \; and \; V_{OH} \; are \; the \; typical \; output \; voltage \; drop \; that \; occur \; with \; the output load. \end{array}$ 





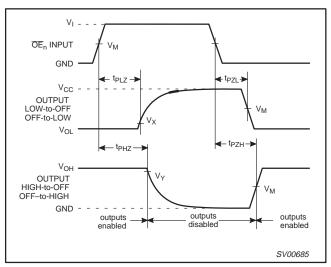


Figure 2. 3-state enable and disable times.

## **TEST CIRCUIT**

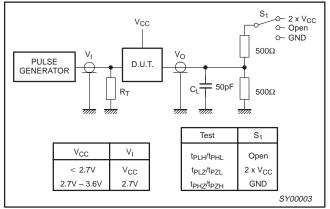
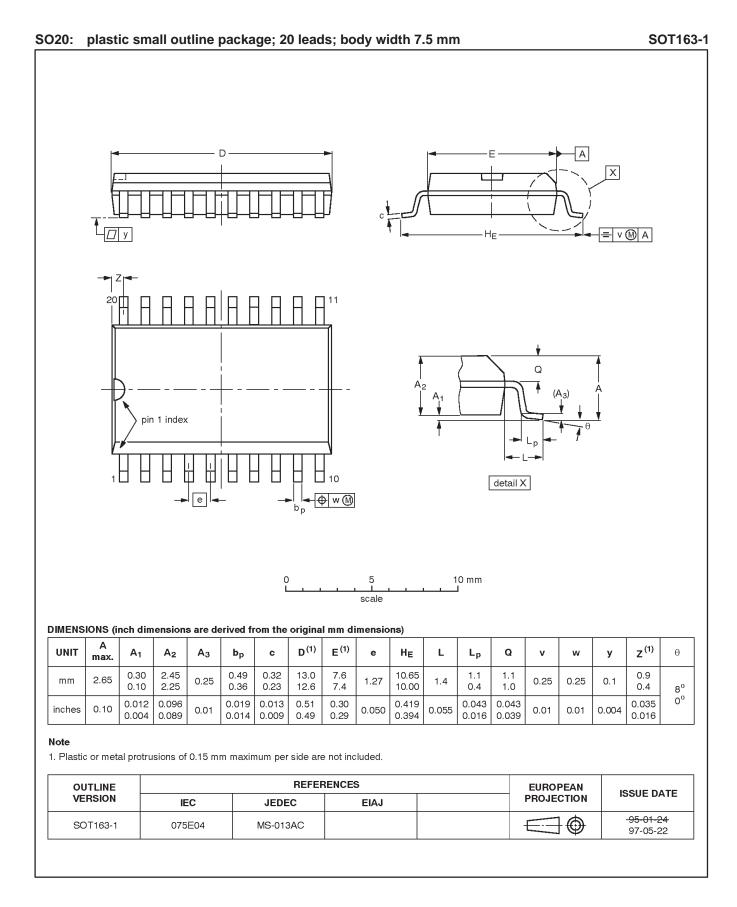
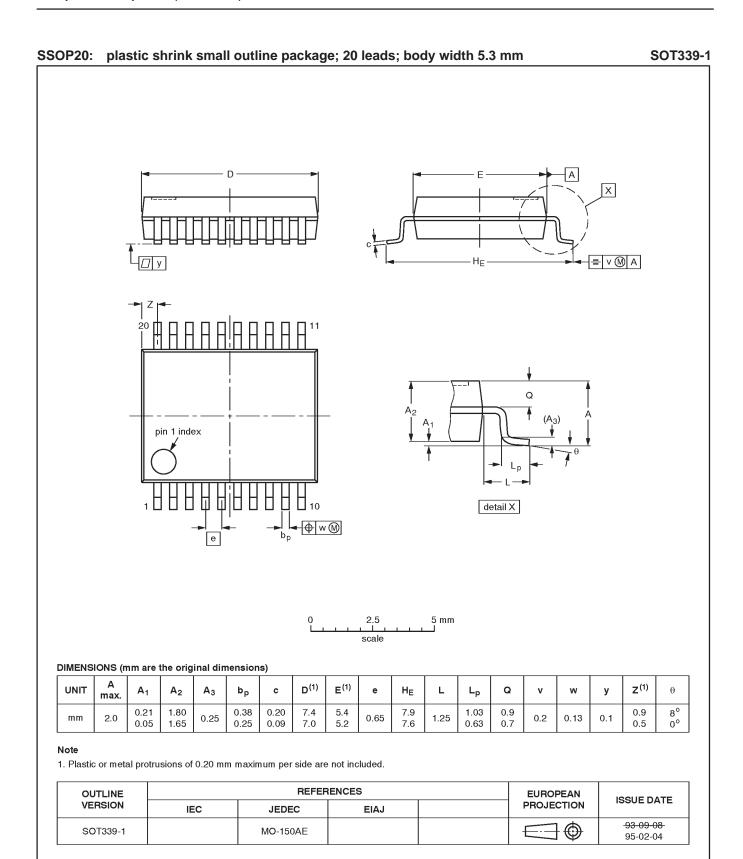


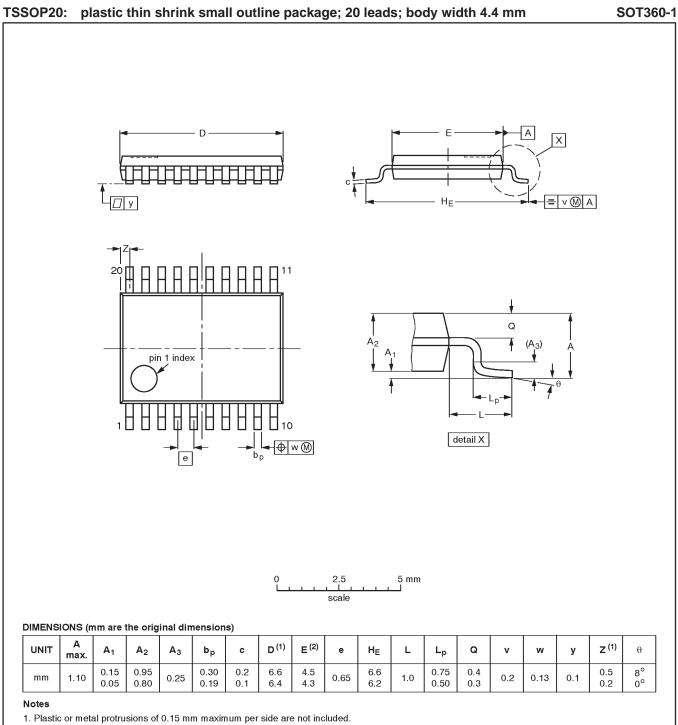
Figure 3. Load circuitry for switching times.





# Octal buffer/line driver with 5-volt tolerant inputs/outputs (3-State)

## 74LVC541A



2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFERENCES			EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT360-1		MO-153AC				<del>-93-06-16</del> 95-02-04

# Octal buffer/line driver with 5-volt tolerant inputs/outputs (3-State)

#### Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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